Improvement of Efficiency in CdS Quantum Dots Sensitized Solar Cells

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CdS quantum dots were coated on TiO\textsubscript{2} layer by successive ionic layer adsorption and reaction method. An efficient photovoltaic energy conversion and significant quantum-size effect were observed. The magnitude of the short-circuit photocurrent density \(J_{SC}\) was found to be approximately 6.01 mA/cm\(^2\) for graphene oxide-incorporated CdS/TiO\textsubscript{2} solar cell, while the \(J_{SC}\) of only CdS-sensitized solar cells was lower than 4.40 mA/cm\(^2\). The efficiency of the CdS/TiO\textsubscript{2} solar cell with a graphene oxide layer containing CdS QDs was 60\% higher than that of the CdS/TiO\textsubscript{2} solar cell. The cell efficiency was remarkably improved with the graphene oxide-incorporation. The carrier recombination of the QDs sensitized solar cells based on CdS-coated TiO\textsubscript{2} was significantly suppressed due to photogenerated charge carrier transports resulting from the presence of graphene oxide.

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1. Introduction

Due to its large band gap (anatase 3.2 eV, rutile 3.0 eV), TiO\textsubscript{2} has a disadvantage in its use as an ideal photoelectrode. There are many attempts to reduce the band gap of TiO\textsubscript{2} [1–5]. However, TiO\textsubscript{2} has potential application due to its excellent photocatalytic activity and long-term chemical stability [6–9]. TiO\textsubscript{2} is the critical component of the dye-sensitized solar cell (SC) [10]. Sambur et al. [11] reported that an improvement of the collection of photocurrents with quantum yields greater than one electron per photon in a photocathodic system, composed of PbS nanocrystals chemically bound to TiO\textsubscript{2} single crystals.

Quantum dots (QDs) sensitized solar cells are the new production solar cells that contain photovoltaic technologies having multiple layers [12]. QDs are used as the absorbing photovoltaic material and their energy gaps can be adjusted by changing the QD size. These properties are the potential benefits of QDs. The application of PbS as a sensitizer in SCs has been reported by many researchers [13–17]. PbS sensitizer in QDSCs is faced with problems such as poor stability and high recombination which lead to low performance. To overcome these problems, the direct growth of a CdS coating layer on previously deposited PbS is beneficial compared with that sensitized by only PbS nanoparticles [18]. Cadmium sulphide (CdS) belonging to the II–VI group has indicated much promise as an effective QD sensitizer due to the suitability of its band gap (2.4 eV) to TiO\textsubscript{2} [19]. Mali et al. [20] have loaded CdS nanoparticles on titanium oxide nanocorals (TNC) using successive ionic layer adsorption and reaction (SILAR) method. They obtained a power conversion efficiency of 0.72\% for TiO\textsubscript{2}–CdS electrodes. This indicates that a good passiv ation layer minimizes the recombination of the charge carriers in the solar cells.

Graphene is an attracting material, which has optical transmittance of 97.7\% [21]. It is one of the excellent transport materials due to its low electron-phonon scattering and high carrier mobility. Graphene oxide (GO) was reported replacing PEDOT:PSS as a layer, which provides hole transporting in polymer solar cells [22, 23]. Photocurrent density measurements in NiO-based dye sensitized solar cells indicate that recombination of photogenerated charges depends on the presence of graphene [24]. Liu et al. [25] reported a single-layer graphene as the top electrodes of semitransparent organic solar cells. They found a maximum efficiency of about 1.4\%, corresponding to a thickness of about 410 nm.

In the present paper, we studied the graphene oxide effects on the efficiency of CdS quantum dots sensitized solar cell. TiO\textsubscript{2} was fabricated using the sol–gel method, which is a simple and fast way to obtain the oxide layer. The graphene oxide powder was distributed onto the surface of CdS coated TiO\textsubscript{2} film. Overall power conversion efficiency of quantum dots sensitized solar cell based on CdS coated TiO\textsubscript{2} is much higher than those of only CdS-sensitized solar cell.

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2. Experimental details

TiO$_2$ nanopowders were prepared by sol-gel method. The used precursors are titanium tetraisopropoxide (TTIP), distilled water, ethyl alcohol (EtOH) and hydrochloric acid (HCl). TiO$_2$ powders were prepared for the various volume ratios. The volume ratio of TTIP:EtOH:H$_2$O:HCl was 1:15:60:2. Titanium tetraisopropoxide was dissolved in water, alcohol and acid solution under stirring for 48 h at room temperature. The prepared solution was precipitated and the obtained powders were filtered and dried at 50°C for 2 h and annealed at 400°C for 3 h. For preparation TiO$_2$ paste, 1 g of TiO$_2$ powders in 1.8 ml of DI water, 30 μl of acetylacetone and 30 μl of terpineol was milled for 1 h and then the stirring was continued for 8 h. The tin doped fluorine (FTO substrate) (10 Ω/square) coated on glass substrate was purchased from Sigma-Aldrich company. This substrate was used as ohmic contact electrode. Before TiO$_2$ paste was coated on FTO substrate, the FTO substrate was cleaned ultrasonically in methanol, acetone and DI water for 5 min. The TiO$_2$ paste was deposited on a FTO glass by doctor blade method. The prepared TiO$_2$ layer was sintered at 500°C for 1 h in air. The CdS quantum dots were deposited on TiO$_2$ layer by SILAR method. The solutions of 0.5 M Cd(NO$_3$)$_2$ in ethanol and 0.5 M Na$_2$S in methanol were prepared. The TiO$_2$ layer was dipped into 0.5 M Cd(NO$_3$)$_2$ solution for 30 s and rinsed with ethanol and then, dipped into 0.5 M Na$_2$S for 30 s and rinsed with methanol. These dipping procedures are considered as one cycle. The coating procedure was repeated for 5 times [26, 27]. The polysulfide (redox couple, $S^2-/S_n^-$) electrolyte was prepared using 0.5 M Na$_2$S, 2 M S, and 0.2 M KCl. Graphene oxide (GO) was prepared by the modified Hummers method [28]. To synthesize GO, 2 g graphite was dissolved in 250 ml H$_2$SO$_4$ in ice bath and 8 g K$_2$MnO$_4$ and 1 g NaNO$_3$ were added to this solution while stirring. The solution was transferred to water bath at 30°C. After 20 min stirring, 250 ml de-ionized water was slowly added and temperature was raised to 98°C and the solution was kept at this temperature for 30 min. The reaction was terminated by adding de-ionized water (300 ml) and followed by the addition of 40 ml of 35% H$_2$O$_2$ solution. The color of the solution was changed to brilliant yellow. The obtained powder was washed and filtered and dried at 50°C for 2 days. To improve the efficiency of solar cell, GO powder was distributed onto the surface of CdS coated TiO$_2$ layer and the electrical characteristics of the prepared solar cell were measured using a KEITHLEY 4200 semiconductor characterization system.

3. Results and discussion

3.1. Photovoltaic performance of CdS quantum dots solar cells

The photovoltaic performance of the solar cell was examined under various illuminations. For the CdS/TiO$_2$ nanostuctured solar cell exposed to solar flux, the following process occurs [29]:

$$\text{CdS} \rightarrow \text{CdS}^+(h^+ + e^-), \quad (1)$$

$$\text{CdS}^+(h^+ + e^-) + \text{TiO}_2 \rightarrow \text{CdS}(h) + \text{TiO}_2(e^-), \quad (2)$$

$$\text{CdS}(h) + S^{2-} \rightarrow \text{CdS}^+ + S_n^{2-}, \quad (3)$$

where $S^{2-}/S_n^{2-}$ is the redox couple for CdS/TiO$_2$ sample obtained from the polysulfide electrolyte, which is prepared using Na$_2$S, S, and KCl. The current density dependence of illumination intensity is shown in Fig. 1. As seen in Fig. 1, the current density increases with increasing light illumination intensity. Also, one can observe that the incorporation of graphene-oxide in CdS/TiO$_2$ solar cell increased the photocurrent density by 37.5% to reach 5.82 mA/cm$^2$ under 100 mW/cm$^2$.

![Figure 1. Photocurrent density-voltage characteristic for CdS/TiO$_2$ solar cells with the CdS SILAR cycles.](image-url)

Figure 2 shows the photosensitivity of the solar cell based on CdS coated TiO$_2$ with variation of short-circuit photocurrent density ($J_{SC}$) vs. the incident irradiation power ($P$). As seen in Fig. 2, the $J_{SC}$ can be analyzed by a power law function, i.e., $J_{SC} \propto P^{m}$ [30]. The value of $m$, which depends on the charge recombination, was found to be 1.20±0.2. This value of $m$ indicates the presence of lower density of trapping centers and, therefore, a perfect material with a more regular structure [31–33]. The obtained $m$ value higher than unity implies that the photoconductivity of the solar cell is controlled by the supralinear recombination [34, 35]. Graphene oxide-incorporated CdS/TiO$_2$ solar cell gives a short-circuit photocurrent density ($J_{SC}$) of 6.01 mA/cm$^2$ and an open-circuit voltage ($V_{OC}$) of 0.346 V, while only CdS/TiO$_2$ solar cell reveals a $J_{SC}$ of 4.4 mA/cm$^2$ and $V_{OC}$ of 0.31 V. As seen in Figs. 2 and 3, both $J_{SC}$ and $V_{OC}$ values of the CdS/TiO$_2$ solar cell show an increment with the graphene oxide on the CdS surface. With the presence of graphene oxide layer, the cell efficiency was increased from about 1.42% to 2.02%, and the fill factor was decreased from 1.64% to 0.31%. The main drawback of these solar cells is their relatively poor fill factor. Lee and Chang [30] have reported a CdS quantum dot-sensitized solar cell that ex-
hibited a poor fill factor in cell performance, considering the penetration of the polysulfide electrolyte in a mesoscopic TiO$_2$ film. They indicated that the composition of the polysulfide redox electrolyte could control the value of fill factor. This means that there is a need to layer that contains hole with optimal redox couple.

Fig. 2. Variation of $J_{SC}$ vs. $P$ for CdS/TiO$_2$ solar cells.

Fig. 3. Variation of $V_{OC}$ vs. $P$ for CdS/TiO$_2$ solar cells.

Sev eral factors eectiv ely impro v e the p erformance of quan tum-dot-sensitized solar cells. One of them is the coun ter electro de. A highly ecien t quan tum dot sensitized solar cell has b een fabricated with ordered mesocellular carbon foam (MSU-F-C) as a coun ter elec- tro de (CE). The cell with MSU-F-C CE yielded the highest p o w er conversion eciency of 3.60% [37]. Xu et al. [38] explored the application of Cu$_2$ZnSnS$_4$ (CZTS) mi-
crospheres as an eectiv e coun ter electro de material for high-eciency quan tum dot sensitized solar cells. The cell with the CZTS microspheres presen ts a p o w er con-
v ersion eciency of 3.73%.

In the present work, Pt deposited glass is used as a coun ter electro de. Pt exhibits p o or electro catalytic ac-
tivit y. It exhibits a lo w er hole-reco v ery rate b et w en the coun ter electro de/p olysulfide electrolyte in-
terface and leads to inecien t cell p erformance. Ecien t c harge sep-

cation whic h pro vides high photocurrent density is attributed to a ZnS passivation layer before and after a PbS layer [39]. The charge-transfer and recombination for photogenerated charges in QD SCs depend on surface treatment [40]. Distribution of graphene oxide onto the surface of CdS coated TiO$_2$ film can reduce electron-hole recombination in the interface and redirect charges, flow-
ing back into the solar cells to produce anodic current. The electron–hole recombination is a measure of loss-rate of the power conversion efficiency for the solar cells. For example, when electrons and holes recombine, the con-

Fig. 4. Equivalent circuit of a solar cell.

Fig. 5. P o w er vs. v oltage plots for the fabricated solar cell at dieren t ligh t in tensit y .

The schematic structure of the prepared solar cell is sho wn in Fig. 4. It is possible to determine the output current of the solar cell under solar radiation with photo-

induced current ($I_0 = I_{Ph} - I_d$). The output power of
the solar cell is highly affected by parameters, such as sunlight intensity and direction of the cells. A solar cell responds to stimulation with incoming sunlight by transmitting a current. The power–voltage characteristics obtained using the photocurrent–voltage data of the solar cell are shown in Fig. 5. As seen in Fig. 5, the output power of the solar cell rises up to a certain voltage value and then, decreases. With increasing light intensity, the output power increases. Moreover, the output power of graphene oxide-incorporated CdS/TiO$_2$ solar cell was increased almost fifteen times compared with the solar cell without graphene oxide layer.

3.2. Capacitance–voltage characteristics of the DSSC

Alternating current (a.c.) characteristics of a solar cell array, especially its capacitance is important. The variations of capacitance with applied voltage at low and high frequencies for the CdS/TiO$_2$ solar cell are shown in Fig. 6. The impedance characteristics on the CdS/TiO$_2$ solar cell indicate that capacitances increase from short circuit region to 0.72 V at low frequency. After 30 kHz, the solar cell exhibits a negative capacitance. This behaviour can be attributed to the large current which flows through the solar cell in reverse bias. A large current observed at potentials below 0.0 V is assigned to a charge injection between the energy levels of CdS and TiO$_2$ [41].

![Graph](image)

Fig. 6. Capacitance–voltage (C–V) curves at different frequencies.

4. Conclusions

In this study, TiO$_2$ nanopowders were prepared by sol-gel method. The efficiency in quantum dot sensitized CdS/TiO$_2$ solar cell exhibited an increase of approximately 60% compared with sensitized by only CdS/TiO$_2$. The efficiency of 2.02% was obtained for the studied solar cell. With graphene oxide incorporation, CdS quantum dots sensitized solar cell exhibited a high photocurrent density of 6.01 mA cm$^{-2}$. The obtained results suggest that the graphene oxide can be a promising material for quantum dots sensitized solar cells.

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References